

Abhay Pasupathy

List of Publications by Year in descending order

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92

papers

11,789

citations

38742

50

h-index

43889

91

g-index

98

all docs

98

docs citations

98

times ranked

12944

citing authors

#	ARTICLE	IF	CITATIONS
1	Extracting the Strain Matrix and Twist Angle from the Moiré Superlattice in van der Waals Heterostructures. ACS Nano, 2022, 16, 1471-1476.	14.6	10
2	Visualizing the unusual spectral weight transfer in DyBa ₂ Cu ₃ O ₇ thin film. Scientific Reports, 2022, 12, 830.	3.3	1
3	Nano-spectroscopy of excitons in atomically thin transition metal dichalcogenides. Nature Communications, 2022, 13, 542.	12.8	23
4	Nanometer-Scale Lateral p-n Junctions in Graphene/RuCl ₃ Heterostructures. Nano Letters, 2022, 22, 1946-1953.	9.1	25
5	Orderly disorder in magic-angle twisted trilayer graphene. Science, 2022, 376, 193-199.	12.6	63
6	Moiré nematic phase in twisted double bilayer graphene. Nature Physics, 2022, 18, 196-202.	16.7	51
7	Coupling between magnetic order and charge transport in a two-dimensional magnetic semiconductor. Nature Materials, 2022, 21, 754-760.	27.5	60
8	Visualizing Atomically Layered Magnetism in CrSBr. Advanced Materials, 2022, 34, e2201000.	21.0	22
9	Topological electronic structure of YbMg ₂ Bi ₂ and CaMg ₂ Bi ₂ . Npj Quantum Materials, 2022, 7, .	5.2	7
10	Nanoscale Femtosecond Dynamics of Mott Insulator (Ca _{0.99} Sr _{0.01}) ₂ RuO ₄ . Nano Letters, 2022, 22, 5689-5697.	9.1	5
11	Moiré metrology of energy landscapes in van der Waals heterostructures. Nature Communications, 2021, 12, 242.	12.8	60
12	Intrinsic donor-bound excitons in ultraclean monolayer semiconductors. Nature Communications, 2021, 12, 871.	12.8	29
13	Deep moiré potentials in twisted transition metal dichalcogenide bilayers. Nature Physics, 2021, 17, 720-725.	16.7	124
14	Moiré heterostructures as a condensed-matter quantum simulator. Nature Physics, 2021, 17, 155-163.	16.7	317
15	Enhanced Superconductivity in Monolayer Ti _d -MoTe ₂ . Nano Letters, 2021, 21, 2505-2511.	9.1	49
16	Electric-field-tunable electronic nematic order in twisted double-bilayer graphene. 2D Materials, 2021, 8, 034005.	4.4	23
17	Nano-imaging of strain-tuned stripe textures in a Mott crystal. Npj Quantum Materials, 2021, 6, .	5.2	12
18	A tell-tale wiggle. Nature Physics, 2021, 17, 1082-1083.	16.7	3

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19	Andreev Reflections in NbN/Graphene Junctions under Large Magnetic Fields. <i>Nano Letters</i> , 2021, 21, 8229-8235.	9.1	3
20	Nanoscale lattice dynamics in hexagonal boron nitride moiré superlattices. <i>Nature Communications</i> , 2021, 12, 5741.	12.8	34
21	Quantum criticality in twisted transition metal dichalcogenides. <i>Nature</i> , 2021, 597, 345-349.	27.8	163
22	Moiréless correlations in ABCA graphene. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2021, 118, .	7.1	59
23	Nonmonotonic Temperature-Dependent Dissipation at Nonequilibrium in Atomically Thin Clean-Limit Superconductors. <i>Nano Letters</i> , 2021, 21, 583-589.	9.1	3
24	High carrier mobility in graphene doped using a monolayer of tungsten oxyselenide. <i>Nature Electronics</i> , 2021, 4, 731-739.	26.0	41
25	Deep Learning Analysis of Polaritonic Wave Images. <i>ACS Nano</i> , 2021, 15, 18182-18191.	14.6	10
26	Excitons in strain-induced one-dimensional moiré potentials at transition metal dichalcogenide heterojunctions. <i>Nature Materials</i> , 2020, 19, 1068-1073.	27.5	169
27	Imaging strain-localized excitons in nanoscale bubbles of monolayer WSe ₂ at room temperature. <i>Nature Nanotechnology</i> , 2020, 15, 854-860.	31.5	134
28	Layered Antiferromagnetism Induces Large Negative Magnetoresistance in the van der Waals Semiconductor CrSBr. <i>Advanced Materials</i> , 2020, 32, e2003240.	21.0	116
29	Complete Strain Mapping of Nanosheets of Tantalum Disulfide. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 43173-43179.	8.0	6
30	Correlated electronic phases in twisted bilayer transition metal dichalcogenides. <i>Nature Materials</i> , 2020, 19, 861-866.	27.5	544
31	Visualization of moiré superlattices. <i>Nature Nanotechnology</i> , 2020, 15, 580-584.	31.5	187
32	Tunable strain soliton networks confine electrons in van der Waals materials. <i>Nature Physics</i> , 2020, 16, 1097-1102.	16.7	47
33	Dictionary learning in Fourier-transform scanning tunneling spectroscopy. <i>Nature Communications</i> , 2020, 11, 1081.	12.8	10
34	Enabling room temperature ferromagnetism in monolayer MoS ₂ via in situ iron-doping. <i>Nature Communications</i> , 2020, 11, 2034.	12.8	112
35	Fragility of the dissipationless state in clean two-dimensional superconductors. <i>Nature Physics</i> , 2019, 15, 947-953.	16.7	29
36	Maximized electron interactions at the magic angle in twisted bilayer graphene. <i>Nature</i> , 2019, 572, 95-100.	27.8	644

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37	Atomic-Scale Characterization of Graphene $\text{p}\text{--}\text{n}$ Junctions for Electron-Optical Applications. <i>ACS Nano</i> , 2019, 13, 2558-2566.	14.6	10
38	Approaching the Intrinsic Limit in Transition Metal Diselenides via Point Defect Control. <i>Nano Letters</i> , 2019, 19, 4371-4379.	9.1	161
39	Sensitivity of the superconducting state in thin films. <i>Science Advances</i> , 2019, 5, eaau3826.	10.3	54
40	Unconventional scaling of the superfluid density with the critical temperature in transition metal dichalcogenides. <i>Science Advances</i> , 2019, 5, eaav8465.	10.3	20
41	Impact of substrate induced band tail states on the electronic and optical properties of MoS ₂ . <i>Applied Physics Letters</i> , 2019, 115, .	3.3	24
42	Via Method for Lithography Free Contact and Preservation of 2D Materials. <i>Nano Letters</i> , 2018, 18, 1416-1420.	9.1	59
43	Superatomic Two-Dimensional Semiconductor. <i>Nano Letters</i> , 2018, 18, 1483-1488.	9.1	41
44	Temperature-driven topological transition in 1T'-MoTe ₂ . <i>Npj Quantum Materials</i> , 2018, 3, .	5.2	36
45	Infrared nanoimaging of the metal-insulator transition in the charge-density-wave van der Waals material 1T'-TaS ₂ . <i>Physical Review B</i> , 2018, 97, .	3.2	9
46	Magnetism in semiconducting molybdenum dichalcogenides. <i>Science Advances</i> , 2018, 4, eaat3672.	10.3	92
47	Strain Engineering and Raman Spectroscopy of Monolayer Transition Metal Dichalcogenides. <i>Chemistry of Materials</i> , 2018, 30, 5148-5155.	6.7	92
48	Band structure engineering of 2D materials using patterned dielectric superlattices. <i>Nature Nanotechnology</i> , 2018, 13, 566-571.	31.5	157
49	Engineering the Structural and Electronic Phases of MoTe ₂ through W Substitution. <i>Nano Letters</i> , 2017, 17, 1616-1622.	9.1	128
50	Signatures of the topological $s + \bar{s}$ superconducting order parameter in the type-II Weyl semimetal T-d-MoTe ₂ . <i>Nature Communications</i> , 2017, 8, 1082.	12.8	101
51	Passivating 1T'-MoTe ₂ multilayers at elevated temperatures by encapsulation. <i>Nanoscale</i> , 2017, 9, 13910-13914.	5.6	7
52	Absence of a Band Gap at the Interface of a Metal and Highly Doped Monolayer MoS ₂ . <i>Nano Letters</i> , 2017, 17, 5962-5968.	9.1	37
53	On the Global Geometry of Sphere-Constrained Sparse Blind Deconvolution. , 2017, .	26	
54	Mapping Periodic Lattice Distortions in Exfoliated Dichalcogenides with Atomic Resolution cryo-STEM. <i>Microscopy and Microanalysis</i> , 2016, 22, 1550-1551.	0.4	0

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55	Thickness and Stacking Sequence Determination of Exfoliated Dichalcogenides Using Scanning Transmission Electron Microscopy. <i>Microanalysis</i> , 2016, 22, 1456-1457.	0.4	0
56	Imaging chiral symmetry breaking from Kekul� bond order in graphene. <i>Nature Physics</i> , 2016, 12, 950-958.	16.7	111
57	Atomic-Scale Spectroscopy of Gated Monolayer MoS ₂ . <i>Nano Letters</i> , 2016, 16, 3148-3154.	9.1	30
58	Atomic lattice disorder in charge-density-wave phases of exfoliated dichalcogenides (1T-TaS) Tj ETQqO 0 0 rgBT /Overlock 10 Tf 50 627 T 113, 11420-11424.	7.1	86
59	Distinct surface and bulk charge density waves in ultrathin $\text{S}_{2\sqrt{3}}$ Physical Review B, 2016, 94, .	3.2	41
60	Klein tunnelling and electron trapping in nanometre-scale graphene quantum dots. <i>Nature Physics</i> , 2016, 12, 1069-1075.	16.7	150
61	Atomistic Interrogation of N Co-dopant Structures and Their Electronic Effects in Graphene. <i>ACS Nano</i> , 2016, 10, 6574-6584.	14.6	53
62	Nature of the quantum metal in a two-dimensional crystalline superconductor. <i>Nature Physics</i> , 2016, 12, 208-212.	16.7	228
63	Flicker Noise as a Probe of Electronic Interaction at Metal Single Molecule Interfaces. <i>Nano Letters</i> , 2015, 15, 4143-4149.	9.1	109
64	Experimental Evidence for a Bragg Glass Density Wave Phase in a Transition-Metal Dichalcogenide. <i>Physical Review Letters</i> , 2015, 114, 026802.	7.8	25
65	Dopant Segregation in Polycrystalline Monolayer Graphene. <i>Nano Letters</i> , 2015, 15, 1428-1436.	9.1	19
66	Quasiparticle Interference, Quasiparticle Interactions, and the Origin of the Charge Density Wave in H ₂ Physical Review Letters, 2015, 114, 037001.	7.8	67
67	Emergent surface superconductivity in the topological insulator Sb ₂ Te ₃ . <i>Nature Communications</i> , 2015, 6, 8279.	12.8	53
68	Structure and control of charge density waves in two-dimensional 1T-TaS ₂ . <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2015, 112, 15054-15059.	7.1	205
69	Visualization of electron nematicity and unidirectional antiferroic fluctuations at high temperatures in NaFeAs. <i>Nature Physics</i> , 2014, 10, 225-232.	16.7	158
70	Segregation of Sublattice Domains in Nitrogen-Doped Graphene. <i>Journal of the American Chemical Society</i> , 2014, 136, 1391-1397.	13.7	86
71	Visualizing the charge density wave transition in H ₂ NbSe ₃ real space. <i>Physical Review B</i> , 2014, 89, .	3.2	136
72	Local Atomic and Electronic Structure of Boron Chemical Doping in Monolayer Graphene. <i>Nano Letters</i> , 2013, 13, 4659-4665.	9.1	192

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73	Substrate Level Control of the Local Doping in Graphene. <i>Nano Letters</i> , 2013, 13, 1386-1392.	9.1	42
74	Topography, complex refractive index, and conductivity of graphene layers measured by correlation of optical interference contrast, atomic force, and back scattered electron microscopy. <i>Journal of Applied Physics</i> , 2013, 114, 183107.	2.5	5
75	Molecular beam growth of graphene nanocrystals on dielectric substrates. <i>Carbon</i> , 2012, 50, 4822-4829.	10.3	34
76	Large Physisorption Strain in Chemical Vapor Deposition of Graphene on Copper Substrates. <i>Nano Letters</i> , 2012, 12, 2408-2413.	9.1	122
77	Connecting Dopant Bond Type with Electronic Structure in N-Doped Graphene. <i>Nano Letters</i> , 2012, 12, 4025-4031.	9.1	471
78	Visualizing Individual Nitrogen Dopants in Monolayer Graphene. <i>Science</i> , 2011, 333, 999-1003.	12.6	774
79	Mechanical Control of Spin States in Spin-1 Molecules and the Underscreened Kondo Effect. <i>Science</i> , 2010, 328, 1370-1373.	12.6	399
80	Visualizing the formation of the Kondo lattice and the hidden order in URu ₂ Si ₂ . <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2010, 107, 10383-10388.	7.1	176
81	Nanoscale Proximity Effect in the High-Temperature Superconductor Bi ₂ Ca ₂ O _{8+δ} . <i>Physical Review Letters</i> , 2010, 104, 117001.		
82	Extending Universal Nodal Excitations Optimizes Superconductivity in Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} . <i>Science</i> , 2009, 324, 1689-1693.	12.6	107
83	Mapping of the formation of the pairing gap in. <i>Journal of Physics and Chemistry of Solids</i> , 2008, 69, 3034-3038.	4.0	5
84	Electronic Origin of the Inhomogeneous Pairing Interaction in the High- <i>T_c</i> Superconductor Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} . <i>Science</i> , 2008, 320, 196-201.	12.6	186
85	Visualizing pair formation on the atomic scale in the high-T _c superconductor Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} . <i>Nature</i> , 2007, 447, 569-572.	27.8	414
86	From Ballistic Transport to Tunneling in Electromigrated Ferromagnetic Breakjunctions. <i>Nano Letters</i> , 2006, 6, 123-127.	9.1	52
87	Vibration-Assisted Electron Tunneling in C140Transistors. <i>Nano Letters</i> , 2005, 5, 203-207.	9.1	184
88	Mechanically Adjustable and Electrically Gated Single-Molecule Transistors. <i>Nano Letters</i> , 2005, 5, 305-308.	9.1	168
89	Metal-nanoparticle single-electron transistors fabricated using electromigration. <i>Applied Physics Letters</i> , 2004, 84, 3154-3156.	3.3	142
90	The Kondo Effect in the Presence of Ferromagnetism. <i>Science</i> , 2004, 306, 86-89.	12.6	516

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91	Coulomb blockade and the Kondo effect in single-atom transistors. <i>Nature</i> , 2002, 417, 722-725.	27.8	1,902
92	Magnetic Anisotropy Variations and Nonequilibrium Tunneling in a Cobalt Nanoparticle. <i>Physical Review Letters</i> , 2001, 87, 226801.	7.8	57